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Abstract
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Reference

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Ferroelectricity and Tetragonality in Ultrathin PbTiO$_3$ Films

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The evolution of tetragonality with thickness has been probed in epitaxial c-axis oriented PbTiO$_3$ films with thicknesses ranging from 500 down to 24 Å. High resolution x ray pointed out a systematic decrease of the c-axis lattice parameter with decreasing film thickness below 200 Å. Using a first-principles model Hamiltonian approach, the decrease in tetragonality is related to a reduction of the polarization attributed to the presence of a residual unscreened depolarizing field. It is shown that films below 50 Å display a significantly reduced polarization but still remain ferroelectric.

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Since its discovery in 1920 by Valasek [1], ferroelectricity has attracted considerable interest from a fundamental point of view and because of its wide range of potential applications. Ferroelectricity has been historically seen as a collective phenomenon [2] requiring a relatively large critical volume of aligned dipoles. Calculations within the Devonshire-Ginzburg-Landau (DGL) theory had indicated that, as the physical dimensions of a ferroelectric material are reduced, the stability of the ferroelectric state is altered, leading to a relatively large critical size below which ferroelectricity is suppressed in small particles and thin films [3,4]. For instance, in the case of Pb(Zr$_{0.5}$Ti$_{0.5}$)O$_3$ thin films, a critical thickness of ~200 Å had been predicted at room temperature [4]. These predictions appeared to agree with then-current experiments [5]. Recent results, however, suggest a much smaller critical size, with ferroelectricity detected in polymer films down to 10 Å [6] and in perovskite films down to 40 Å (ten unit cells) [7]. X-ray synchrotron studies have revealed periodic 180° stripe domains in 12 to 420 Å thick epitaxial films of PbTiO$_3$ (PTO) grown on insulating SrTiO$_3$ (STO) substrates [8,9]. On the theoretical side, atomistic simulations have emphasized the predominant role of electrostatic boundary conditions in determining ferroelectricity in very thin films. Ghosez and Rabe [10] and Meyer and Vanderbilt [11] showed that, under perfect screening of the depolarizing field, ultrathin stress-free perovskite slabs can sustain a polarization perpendicular to the surface. However, perfect screening is not achieved in usual ferroelectric capacitors. Batra et al. [12,13] showed that, under short-circuit boundary conditions, the incomplete screening of the depolarizing field resulting from the finite screening length of the metal can substantially affect the ferroelectric properties [14]. Consequences of imperfect screening on the coercive field have recently been studied in detail [17]. Also, first-principles calculations allowed the amplitude of the depolarizing field for BaTiO$_3$ ultrathin films between metallic SrRuO$_3$ electrodes in short-circuit conditions to be quantified and a critical thickness of ~24 Å (six unit cells) in such structures to be predicted [18].

These recent experimental and theoretical results, at odds with the former well established belief, clearly show that additional studies are crucial to demonstrate experimentally the key role of screening and confirm ferroelectricity at the nanoscale [19]. In this Letter we report on combined experimental and theoretical investigations of tetragonality in a series of epitaxial c-axis oriented films of PTO grown onto metallic Nb-doped STO substrates. X-ray analyses show that the tetragonality progressively decreases below 200 Å. Using a first-principles-based model Hamiltonian approach, we relate this lowering of tetragonality to a lowering of the spontaneous polarization of the films, due to a residual unscreened depolarizing field. Our results show that ultrathin PTO films on Nb-STO display a significantly reduced spontaneous polarization but still remain ferroelectric below 50 Å.

Two series of PTO films were grown onto metallic (001) 0.5 wt% Nb-STO substrates by off-axis radio-frequency magnetron sputtering [20,21], with 60 and 40 W applied to the Pb$_{1/2}$TiO$_3$ target, corresponding to growth rates of 280 and 110 Å/h, respectively [22].

Room temperature x-ray measurements, using a Philips X’Pert High Resolution diffractometer, allowed us to determine precisely the epitaxy of the films, their thickness, and their c-axis parameter. The θ–2θ diffractograms, revealing only (00l) reflections, demonstrate that the films are purely c axis with the polarization normal to the film surface. Pole figures confirmed the expected epitaxial “cube on cube” growth and that the films were tetragonal. High angle finite-size oscillations and low angle reflectometry [Fig. 1 (top)] allowed us to determine, through simulations, the number of planes involved in the diffraction and thus the film thickness [23] as well as the deposition rate, even for films down to 24 Å. To precisely determine the c-axis parameter, we performed x-ray diffraction for the (00l), l = 1 to 5 reflections as shown in Fig. 1 (middle).

[References]

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cally smooth with a root-mean-square (rms) roughness between 2 and 6 Å over 10 × 10 μm² areas. Figure 2 (left) shows a representative topographic image obtained on a 33 Å thick film. The vertical scale used in this 3D representation is equal to the thickness of the sample, allowing a comparison of the roughness of the surface with the total film thickness. As can be seen from the data, the average thickness remains well defined, even for ultrathin films.

Finally, we used the piezoresponse mode of the AFM to probe the domain structure of different films [26,27]. Ten stripes where drawn using alternate +12 and −12 V voltages applied to the tip over a 1.6 × 1.6 μm² area. The 3.2 × 1.6 μm² background piezoresponse signal was then compared to the signal from the stripes [Fig. 2 (right)] and found to be equal to the signal obtained for the +12 V written stripes suggesting a single polarization in the as grown sample. All the investigated films were found to be “monodomain-like” over the studied areas, typically a few μm².

We now return to the relation between the c-axis parameter and the film thickness. Figure 1 (bottom) is a blowup of diffractograms around the (002) diffraction peaks and allows the change in lattice parameter with film thickness to be directly seen for three samples. Figure 3 shows the central result of the Letter: the film tetragonality, i.e., the c/a ratio, is plotted as a function of film thickness for the two series of samples (top). As can be seen, the data for both series collapse and the c/a ratio decreases very substantially for films thinner than 200 Å.

We note that a similar reduction of tetragonality has recently been observed by Tybell [29]. It has also been checked experimentally that the c-axis values did not change after the deposition of a gold electrode and shortening of the gold electrode and the metallic substrate (ensuring short-circuit conditions).

The observed reduction of c/a shown in Fig. 3 (top) cannot be attributed to a change in the a-axis lattice parameter since it is independent of the film thickness. Instead, the decrease of c must be related to a concomitant reduction of the spontaneous polarization through the polarization-strain coupling that is known to be particularly large in PTO [30]. The evolution of c/a therefore is a signature of the progressive suppression of ferroelectricity in ultrathin films.

This can be highlighted theoretically by extending the first-principles effective Hamiltonian approach developed by Waghmare and Rabe for bulk PTO [31] to thin films. Within this approach, the energy is written as a low-order

Since at room temperature the a-axis lattice parameter of ferroelectric bulk PTO is 3.902–3.904 Å [24,25], very close to the 3.905 Å of the STO, the films are expected to be coherent, with their a axis equal to the STO lattice parameter. Grazing incidence diffraction on a ~86 Å thin film confirmed this picture, displaying a unique (200) reflection. Measurements of the PTO (101) reflection for the thickest films (~504 and ~396 Å) gave an estimation of a = 3.90 ± 0.01 Å. For these films, in-plane strain relaxation would lead to a maximum change in the c-axis length of 0.006 Å, which is ~15 times smaller than the changes discussed below. The a-axis value used later to calculate the c/a ratio is thus taken as constant and equal to 3.905 Å.

To probe finite-size effects in thin films, a key requirement is to have materials with smooth surfaces and therefore a well-defined thickness. Atomic force microscope (AFM) topographic measurements were performed on all the samples, showing that the films are essentially atomically smooth with a root-mean-square (rms) roughness being

![FIG. 1. Top: θ-2θ diffractogram around the (001) diffraction peak for a 396 Å sample (thick line) and simulation (thin line). Inset: low angle θ-2θ diffractogram for the same sample. Middle: θ-2θ diffractogram revealing (001) reflections from l = 1 to 5 for the same 396 Å thick film. Bottom: θ-2θ diffractograms around the (002) diffraction peak for three films of different thicknesses: 396, 132 and 73 Å, respectively, allowing the decrease of the c axis with thickness to be clearly seen.](image1)

![FIG. 2 (color online). Left: AFM topography for a 33 Å thick film. The rms roughness is ~3 Å over the scanned area. The vertical scale is the film thickness. Right: Piezoresponse signal obtained after writing ten stripes using alternate +12 and −12 V voltages applied to the tip.](image2)
Taylor expansion of the bulk energy around the cubic phase within the restricted subspace spanned by (i) the ionic degree of freedom $\xi$ associated to the lattice Wannier function of the soft phonon branch and (ii) the macroscopic strain $e$. The bulk Hamiltonian includes three terms: the double-well soft-mode energy, the elastic energy, and a coupling term between $\xi$ and $e$. All the bulk parameters are obtained by fitting first-principles results.

In Ref. [18], the suppression of the ferroelectricity in ultrathin films between metallic electrodes in short circuit was related to the incomplete screening of the depolarizing field by the electrodes. It was also shown that the energetics of ultrathin films can be reasonably described using a simple model that corrects the bulk internal volume at first order by a term taking into account the energy associated to the coupling between the polarization $P$ and the unscreened depolarizing field $E_d$. Transposing this to the effective Hamiltonian approach allows us to write

$$\mathcal{H}^{\text{film}}(\xi, e) = \mathcal{H}^{\text{bulk}}(\xi, e) - E_d \cdot P,$$  \hspace{1cm} (1)

where $\mathcal{H}^{\text{bulk}}$ and $\mathcal{H}^{\text{film}}$ are the model Hamiltonians for bulk and thin film, respectively. For $\mathcal{H}^{\text{bulk}}$, we keep the form and parameters fitted at the experimental volume as reported in Ref. [31]. Therefore, the only finite-size correction included in $\mathcal{H}^{\text{film}}$ arises from the electrostatic energy related to $E_d$.

Under short-circuit conditions, $E_d$ is related to the potential drop $\Delta V$ at each metal-ferroelectric interface. Assuming two similar interfaces with the top and bottom electrodes, then $E_d = -2\Delta V/d$, where $d$ is the thickness of the film. The potential drop was attributed to finite dipole densities at the interfaces and was shown to evolve linearly with the spontaneous polarization: $\Delta V = (\lambda_{\text{eff}}/\epsilon_0) \cdot P$. The parameter $\lambda_{\text{eff}}$ has the dimension of a length and is referred to as the effective screening length of the system.

Supposing monodomain films polarized along $z$, in agreement with the piezoresponse measurements, the macroscopic polarization is homogeneous and directly linked to $\xi$ ($P_z = Z^z \xi / \Omega_0$ [31], where $Z^z$ is the soft-mode effective charge, $\xi$ is the $z$ component of $\xi$, and $\Omega_0$ is the unit cell volume) so that we finally obtain

$$-E_d \cdot P_z = (2\lambda_{\text{eff}}Z^z/\Omega_0\epsilon_{0d})\xi_z.$$  \hspace{1cm} (2)

This energy scales with $\lambda_{\text{eff}}/d$ and is positive meaning that the effect of the depolarizing field is to suppress the ferroelectric instability through a renormalization of the quadratic term of the effective Hamiltonian.

The previous model is now applied to thin films of PTO on Nb-STO. Perfect pseudomorphic thin films on top of a cubic substrate are considered and the in-plane strains $\varepsilon_{xx} = \varepsilon_{yy} = (a_{\text{STO}} - a_{\text{PTO}})/a_{\text{PTO}}$ with $a_{\text{STO}} = 3.905 \text{ Å}$ and $a_{\text{PTO}} = 3.969 \text{ Å}$ [32] are fixed throughout the structure independently of the film thickness, in order to constrain the $a$-axis lattice constant imposed by the STO substrate. The energy [Eq. (1)] is then minimized for different thicknesses in terms of $\xi_z$ (supposed uniform and perpendicular to the film) and $e_{zz}$. From the values of $\xi_z$ and $e_{zz}$ we deduce $P$ and $c/a$. All the simulations have been carried out at $T = 0$.

First-principles results for the SrRuO$_3$/BaTiO$_3$ interface yield $\lambda_{\text{eff}} = 0.23 \text{ Å}$. Because the screening might be slightly different for the present system composed of distinct interfaces, the theoretical results are reported in Fig. 3 (bottom) for slightly different values of $\lambda_{\text{eff}}$. The model predicts a critical thickness below which the spontaneous polarization vanishes and the $c/a$ ratio of the resulting paraelectric phase saturates at 1.03, as a result of the mechanical constraint imposed by the substrate. Above the critical thickness, the spontaneous polarization gradually increases up to the bulk value as does the $c$-axis lattice parameter, as a consequence of the polarization-strain coupling.

The model Hamiltonian of Waghmare and Rabe, although appropriately describing PTO, is known to overestimate the polarization-strain coupling. At the bulk level, the model predicts $c/a = 1.09$ while the experimental value is equal to $\approx 1.06$ [31]. In order to get rid of this bulk overestimation, and for a direct comparison of the theoretical and experimental evolution of $c/a$, the theoretical curves have been renormalized to give a tetragonality of 1.068 at 500 Å, in agreement with the experimental data. Only the strength of the polarization-strain coupling must be rescaled while the $c/a$ value of the paraelectric phase, a priori properly predicted through the elastic constants, can be kept unchanged.

![FIG. 3. Evolution of the $c/a$ ratio with the film thickness. Top: experimental results for the first series (circles), the second series (squares), and the first series with a gold top electrode (crosses); the dashed line is the phenomenological theory prediction (see the text) supposing a ratio between the extrapolation and the correlation length $\delta/\xi = 1.41$ [28]; the solid line is the model Hamiltonian prediction for $\lambda_{\text{eff}} = 0.12 \text{ Å}$, rescaled to give a maximum tetragonality in agreement with the experimental data. Bottom: results from the model Hamiltonian calculations for $\lambda_{\text{eff}} = 0.23 \text{ Å}$ (dashed line), $\lambda_{\text{eff}} = 0.12 \text{ Å}$ (solid line), and $\lambda_{\text{eff}} = 0.06 \text{ Å}$ (dotted line). Inset: thickness dependence of the spontaneous polarization $P$ calculated from the model Hamiltonian for $\lambda_{\text{eff}} = 0.12 \text{ Å}$.]

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Looking at the experimental points on Fig. 3 (top), both the range of thicknesses at which the $c/a$ ratio starts to decrease and the shape of the evolution agree with the prediction of the model Hamiltonian calculations for $\lambda_{\text{eff}} = 0.12 \, \text{Å}$. This supports an incomplete screening of the depolarizing field as the driving force for a global reduction of the polarization in perovskite ultrathin films. In contrast, the DGL phenomenological theory including only an intrinsic suppression of ferroelectricity at the surface through the so-called extrapolation length parameter $\delta$ [33] predicts a much sharper decay with no substantial decrease of polarization predicted above 50 Å [28]. The value of $\lambda_{\text{eff}}$ (0.12 Å) used in Fig. 3 (top) is smaller than in the case of the BaTiO$_3$/SrRuO$_3$ interface [18] (0.23 Å) (albeit in the same order of magnitude). This might suggest a better screening for the present system but might also be partly attributed to an overestimate of the theoretical critical thickness due to the simplicity of the model Hamiltonian [34] and to the fact that the simulations were performed at $T = 0$.

Importantly, the thinnest films have a much higher trigonality than the value of 1.03 expected for the paraelectric phase from the macroscopic theory of elasticity. No saturation of $c/a$, the signature of a complete suppression of ferroelectricity, was observed, clearly implying that films much thinner than 50 Å are still ferroelectric.

In conclusion, we found that the $c$-axis parameter of PTO films decreases substantially below 200 Å. A first-principles effective Hamiltonian approach allowed us to establish that the lowering of $c/a$ is related to a progressive reduction of the polarization due to an imperfect screening of the depolarizing field. Although their polarization is significantly reduced, the fact that no saturation of the $c$ axis to its paraelectric value was found down to very thin films (24 Å) demonstrates that PTO films below 50 Å remain ferroelectric at room temperature.

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[14] Other models identify the origin of the nonvanishing depolarizing field with an inhomogeneous polarization related to the contribution of surface effects. Kretschmer and Binder [15] and Glinchuk et al. [16] have included effects of surface polarization gradients into the DGL free energy, showing also a strong modification of the ferroelectric properties for thin films.


[22] Higher growth rates were observed for ultrathin films (below 40 Å).


[29] T. Tybell (private communication).


[32] Within $\mathcal{H}_{\text{eff}}$, the strains are defined with reference to the bulk cubic structure.

[33] A modification of the ratio $\delta/e$ does not introduce a major improvement in the agreement with the experiment.

[34] A similar model for BaTiO$_3$ predicts a critical thickness of 35 Å, larger than the first-principles value of 24 Å reported in Ref. [18].